NSN 5962-01-213-2277

Memory Microcircuit - Page 1 of 1



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Body Le	ength:
1.290 ind	ches
Body W	/idth:
0.560 ind	ches
Body He	eight:
0.170 ind	ches
Maximu	Im Power Dissipation Rating:
1.0 watte	S
Operati	ng Tempurature Range:
+0.0/+70	0.0 degrees celsius
Storage	e Tempurature Range:
-65.0/+1	50.0 degrees celsius
Feature	s Provided:
Static op	peration and high performance and programmable and 3-state output
Inclosur	re Material:
Ceramic	c and glass
Inclosur	re Configuration:
Dual-in-l	line
Output I	Logic Form:
N-type m	netal oxide-semiconductor logic
Input Ci	ircuit Pattern:
13 input	
Termina	al Surface Treatment:
Solder	
Voltage	Rating And Type Per Characteristic:
-0.5 volts	s power source and 7.0 volts power source
Time Ra	ating Per Chacteristic:
Err-060	hand pull and err-060 hand
Memory	/ Device Type:
Rom	
Termina	al Type And Quantity:
24 printe	ed circuit
Shelf Lit	fe:
N/a	
Unit Of	Measure:
Demilita	arization:
Yes - de	emil/mli
Fiig:	
A458a0	